

## DS2003/DS9667/DS2004 High Current/Voltage Darlington Drivers

### General Description

The DS2003/DS9667/DS2004 are comprised of seven high voltage, high current NPN Darlington transistor pairs. All units feature common emitter, open collector outputs. To maximize their effectiveness, these units contain suppression diodes for inductive loads and appropriate emitter base resistors for leakage.

The DS2003/DS9667 has a series base resistor to each Darlington pair, thus allowing operation directly with TTL or CMOS operating at supply voltages of 5.0V.

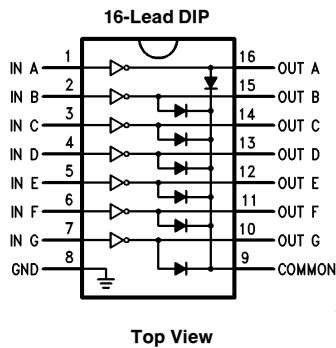
The DS2004 has an appropriate input resistor to allow direct operation from CMOS or PMOS outputs operating from supply voltages of 6.0V to 15V.

The DS2003/DS9667/DS2004 offer solutions to a great many interface needs, including solenoids, relays, lamps, small motors, and LEDs. Applications requiring sink currents beyond the capability of a single output may be accommodated by paralleling the outputs.

### Features

- Seven high gain Darlington pairs
- High output voltage ( $V_{CE} = 50V$ )
- High output current ( $I_C = 350\text{ mA}$ )
- TTL, PMOS, CMOS compatible
- Suppression diodes for inductive loads
- Extended temperature range

### Connection Diagram



TL/F/9647-1

### Order Numbers

	<b>J Package Number J16A</b>	<b>N Package Number N16E</b>	<b>M Package Number M16A</b>
DS2003 DS9667	DS2003MJ DS2003TJ DS2003CJ DS9667MJ DS9667TJ DS9667CJ	DS2003TN DS2003CN DS9667TN DS9667CN	DS2003TM DS2003CM
DS2004	DS2004MJ DS2004TJ DS2004CJ	DS2004TN DS2004CN	DS2004TM DS2004CM

**DS2003/DS9667/DS2004 High Current/Voltage Darlington Drivers**

## Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

### Storage Temperature Range

Ceramic DIP	-65°C to +175°C
Molded DIP	-65°C to +150°C

### Operating Temperature Range

DS2003M/DS9667M	-55°C to +125°C
DS2004M	-55°C to +125°C
DS2003T/DS9667T	-40°C to +105°C
DS2004T	-40°C to +105°C
DS2003C/DS9667C	0°C to +85°C
DS2004C	0°C to +85°C

### Lead Temperature

Ceramic DIP (Soldering, 60 seconds)	300°C
Molded DIP (Soldering, 10 seconds)	265°C

### Maximum Power Dissipation\* at 25°C

Cavity Package	2016 mW
Molded Package	1838 mW
S.O. Package	926 mW

\*Derate cavity package 16.13 mW/°C above 25°C; derate molded DIP package 14.7 mW/°C above 25°C. Derate S.O. package 7.4 mW/°C.

### Input Voltage

30V

### Output Voltage

55V

### Emitter-Base Voltage

6.0V

### Continuous Collector Current

500 mA

### Continuous Base Current

25 mA

## Electrical Characteristics $T_A = 25^\circ\text{C}$ , unless otherwise specified (Note 2)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
$I_{CEX}$	Output Leakage Current	$T_A = 25^\circ\text{C}$ , $V_{CE} = 50\text{V}$ (Figure 1a)			20	$\mu\text{A}$
		$T_A = 85^\circ\text{C}$ , $V_{CE} = 50\text{V}$ (Figure 1a) for Commercial Grade			100	
		$T_A = 25^\circ\text{C}$ , $V_{CE} = 50\text{V}$ , $V_I = 1.0\text{V}$ (Figure 1b) DS2004			500	
$V_{CE(Sat)}$	Collector-Emitter Saturation Voltage	$I_C = 350\text{ mA}$ , $I_B = 500\ \mu\text{A}$ (Figure 2) (Note 3)		1.25	1.6	V
		$I_C = 200\text{ mA}$ , $I_B = 350\ \mu\text{A}$ (Figure 2)		1.1	1.3	
		$I_C = 100\text{ mA}$ , $I_B = 250\ \mu\text{A}$ (Figure 2)		0.9	1.1	
$I_{I(ON)}$	Input Current	$V_I = 3.85\text{V}$ (Figure 3) DS2003/DS9667		0.93	1.35	mA
		$V_I = 5.0\text{V}$ (Figure 3) DS2004		0.35	0.5	
		$V_I = 12\text{V}$ (Figure 3)		1.0	1.45	
$I_{I(OFF)}$	Input Current (Note 4)	$T_A = 85^\circ\text{C}$ for Commercial $I_C = 500\ \mu\text{A}$ (Figure 4)	50	100		$\mu\text{A}$
$V_{I(ON)}$	Input Voltage (Note 5)	$V_{CE} = 2.0\text{V}$ , $I_C = 200\text{ mA}$ (Figure 5) DS2003/DS9667			2.4	V
		$V_{CE} = 2.0\text{V}$ , $I_C = 250\text{ mA}$ (Figure 5)			2.7	
		$V_{CE} = 2.0\text{V}$ , $I_C = 300\text{ mA}$ (Figure 5)			3.0	
		$V_{CE} = 2.0\text{V}$ , $I_C = 125\text{ mA}$ (Figure 5) DS2004			5.0	
		$V_{CE} = 2.0\text{V}$ , $I_C = 200\text{ mA}$ (Figure 5)			6.0	
		$V_{CE} = 2.0\text{V}$ , $I_C = 275\text{ mA}$ (Figure 5)			7.0	
		$V_{CE} = 2.0\text{V}$ , $I_C = 350\text{ mA}$ (Figure 5)			8.0	
$C_I$	Input Capacitance			15	30	pF
$t_{PLH}$	Turn-On Delay	$0.5 V_I$ to $0.5 V_O$			1.0	$\mu\text{s}$
$t_{PHL}$	Turn-Off Delay	$0.5 V_I$ to $0.5 V_O$			1.0	$\mu\text{s}$
$I_R$	Clamp Diode Leakage Current	$V_R = 50\text{V}$ (Figure 6)	$T_A = 25^\circ\text{C}$		50	$\mu\text{A}$
			$T_A = 85^\circ\text{C}$		100	$\mu\text{A}$
$V_F$	Clamp Diode Forward Voltage	$I_F = 350\text{ mA}$ (Figure 7)		1.7	2.0	V

**Note 1:** "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Electrical Characteristics" provide conditions for actual device operation.

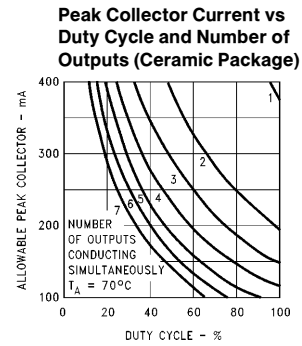
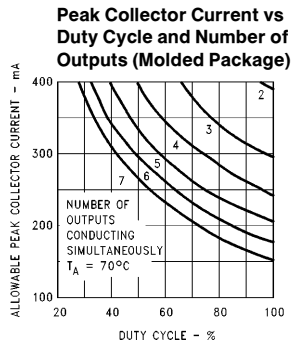
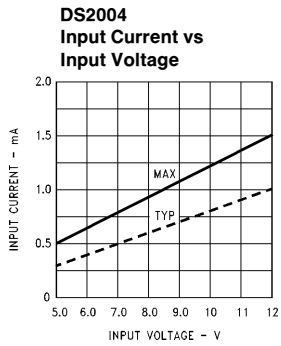
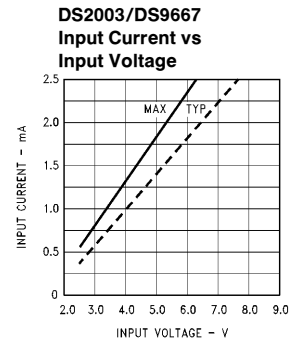
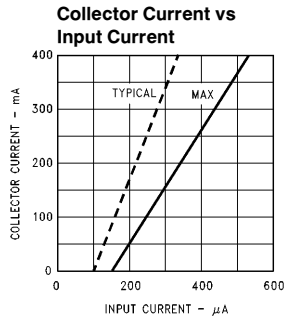
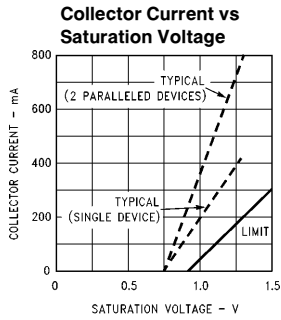
**Note 2:** All limits apply to the complete Darlington series except as specified for a single device type.

**Note 3:** Under normal operating conditions these units will sustain 350 mA per output with  $V_{CE(Sat)} = 1.6\text{V}$  at  $70^\circ\text{C}$  with a pulse width of 20 ms and a duty cycle of 30%.

**Note 4:** The  $I_{I(OFF)}$  current limit guaranteed against partial turn-on of the output.

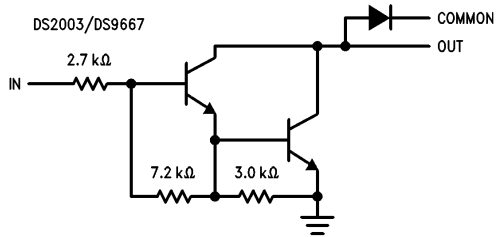
**Note 5:** The  $V_{I(ON)}$  voltage limit guarantees a minimum output sink current per the specified test conditions.

# Typical Performance Characteristics

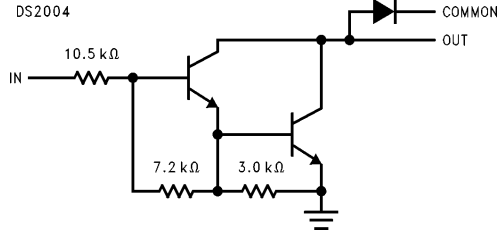


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## Equivalent Circuits

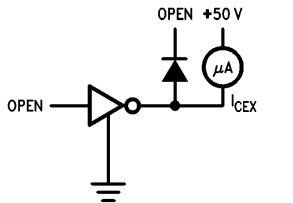


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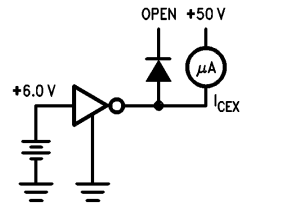
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## Test Circuits



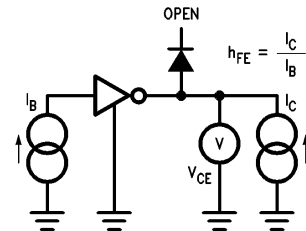
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FIGURE 1a



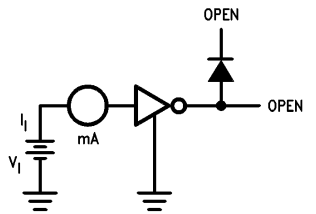
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FIGURE 1b



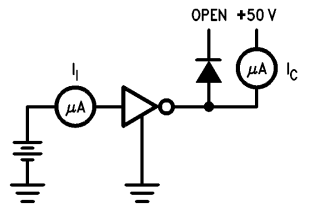
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FIGURE 2



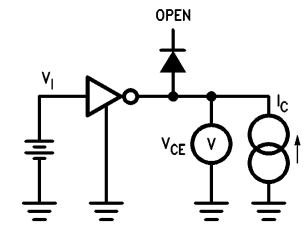
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FIGURE 3



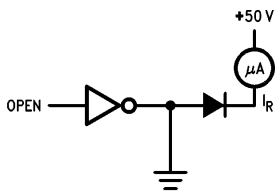
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FIGURE 4



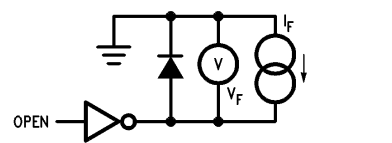
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FIGURE 5



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FIGURE 6

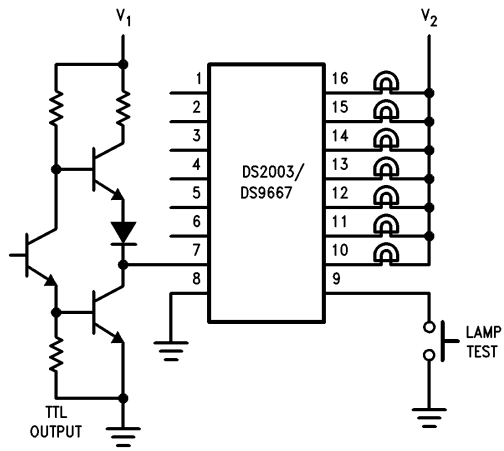


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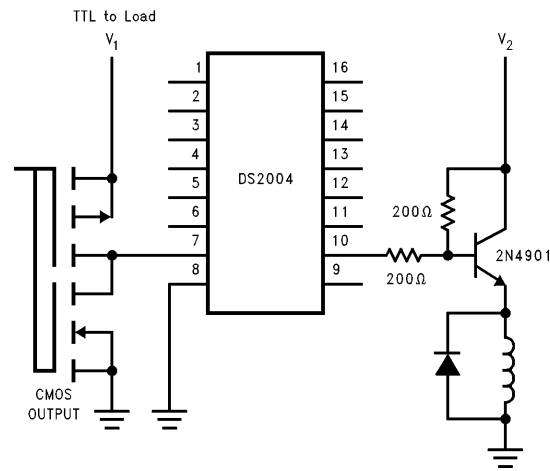
FIGURE 7

## Typical Applications

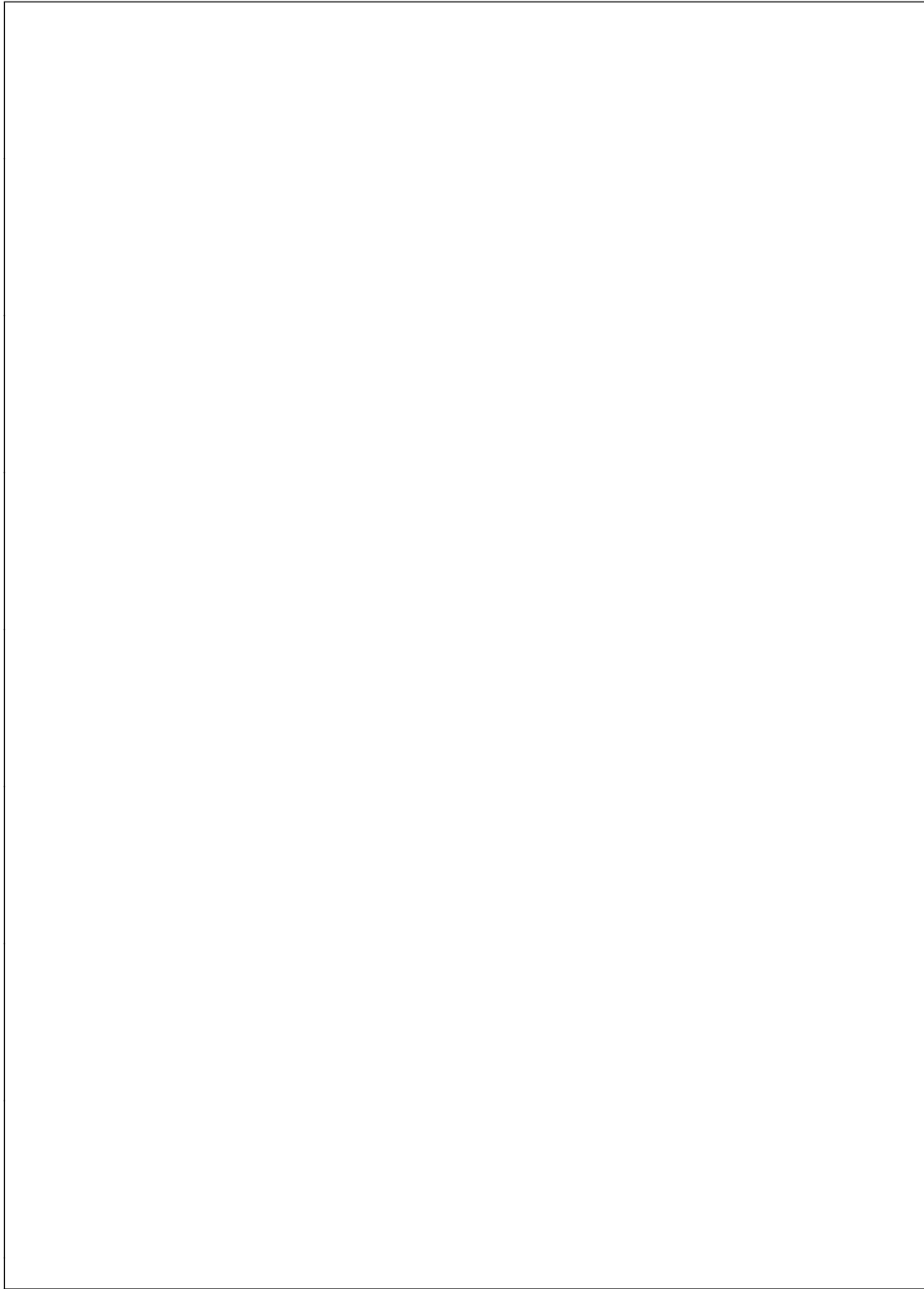
Buffer for Higher Current Loads



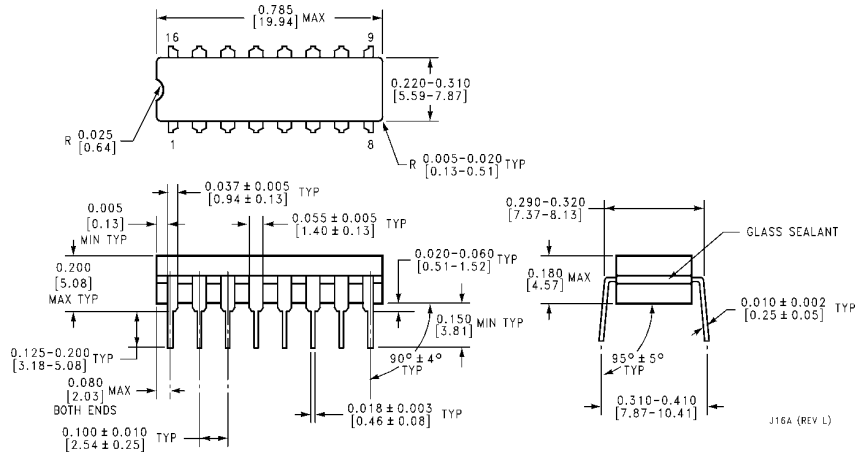
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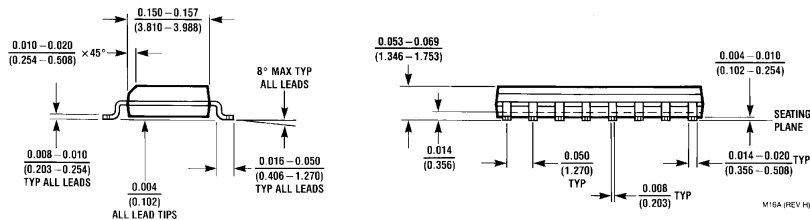
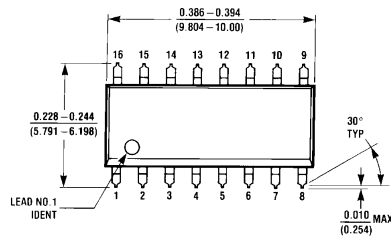
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**Physical Dimensions** inches (millimeters) unless otherwise noted

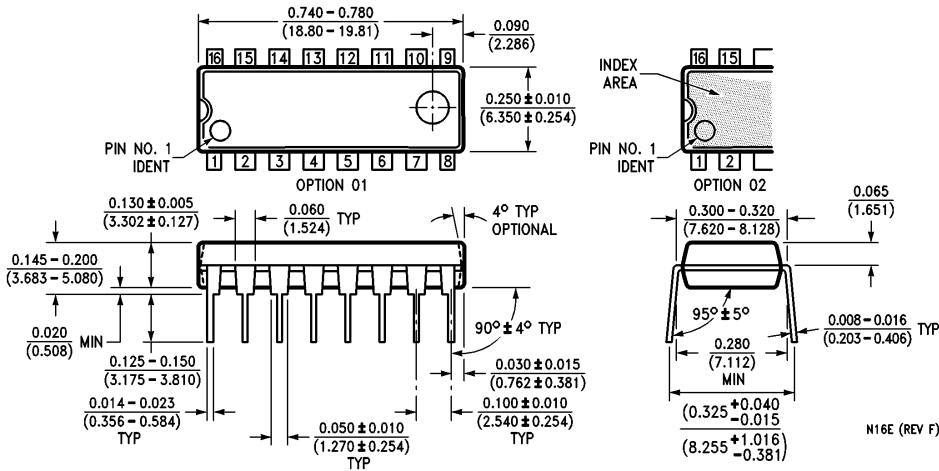


**Ceramic Dual-In-Line Package (J)**  
**Order Number DS2003CJ, DS9667CJ, DS2003MJ, D9667MJ,**  
**DS2003TJ, DS9667TJ, DS2004CJ, DS2004MJ or DS2004TJ**  
**NS Package Number J16A**



**Surface Mount Package (M)**  
**Order Number DS2003CM, DS9667CM, DS2003TM, DS9667TM, DS2004CM or DS2004TM**  
**NS Package Number M16A**

**Physical Dimensions** inches (millimeters) unless otherwise noted (Continued)



**Molded Dual-In-Line Package (N)**

Order Number DS2003CN, DS9667CN, DS2003TN, DS9667TN, DS2004CN or DS2004TN  
NS Package Number N16E

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